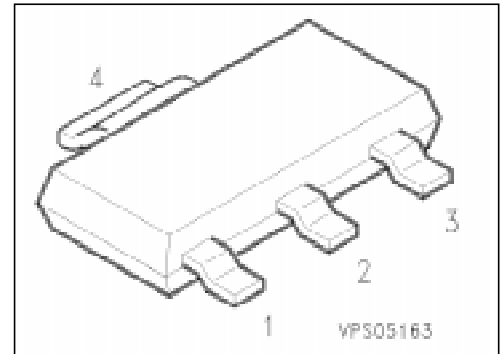


NPN Silicon AF Transistors

BCP 54
... **BCP 56**

- For AF driver and output stages
- High collector current
- Low collector-emitter saturation voltage
- Complementary types: BCP 51 ... BCP 53 (PNP)



| Type | Marking | Ordering Code (tape and reel) | Pin Configuration | | | | Package ¹⁾ |
|-----------|-----------|----------------------------------|-------------------|---|---|---|-----------------------|
| | | | 1 | 2 | 3 | 4 | |
| BCP 54 | BCP 54 | Q62702-C2117 | B | C | E | C | SOT-223 |
| BCP 54-10 | BCP 54-10 | Q62702-C2119 | | | | | |
| BCP 54-16 | BCP 54-16 | Q62702-C2120 | | | | | |
| BCP 55 | BCP 55 | Q62702-C2148 | | | | | |
| BCP 55-10 | BCP 55-10 | Q62702-C2122 | | | | | |
| BCP 55-16 | BCP 55-16 | Q62702-C2123 | | | | | |
| BCP 56 | BCP 56 | Q62702-C2149 | | | | | |
| BCP 56-10 | BCP 56-10 | Q62702-C2125 | | | | | |
| BCP 56-16 | BCP 56-16 | Q62702-C2106 | | | | | |

¹⁾ For detailed information see chapter Package Outlines.

Maximum Ratings

| Parameter | Symbol | Values | | | Unit |
|--|-----------|----------------|--------|--------|------------------|
| | | BCP 54 | BCP 55 | BCP 56 | |
| Collector-emitter voltage $R_{BE} \leq 1 \text{ k}\Omega$ | V_{CE0} | 45 | 60 | 80 | V |
| | V_{CER} | 45 | 60 | 100 | |
| Collector-base voltage | V_{CB0} | 45 | 60 | 100 | |
| Emitter-base voltage | V_{EB0} | 5 | | | |
| Collector current | I_C | 1 | | | A |
| Peak collector current | I_{CM} | 1.5 | | | |
| Base current | I_B | 100 | | | mA |
| Peak base current | I_{BM} | 200 | | | |
| Total power dissipation, $T_S = 124 \text{ }^\circ\text{C}^{1)}$ | P_{tot} | 1.5 | | | W |
| Junction temperature | T_j | 150 | | | $^\circ\text{C}$ |
| Storage temperature range | T_{stg} | - 65 ... + 150 | | | |

Thermal Resistance

| | | | |
|----------------------------------|---------------------|-----------|-----|
| Junction - ambient ¹⁾ | $R_{th \text{ JA}}$ | ≤ 72 | K/W |
| Junction - soldering point | $R_{th \text{ JS}}$ | ≤ 17 | |

¹⁾ Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm² Cu.

Electrical Characteristics

at $T_A = 25\text{ °C}$, unless otherwise specified.

| Parameter | Symbol | Values | | | Unit |
|-----------|--------|--------|------|------|------|
| | | min. | typ. | max. | |

DC characteristics

| | | | | | |
|---|---------------|-----------------------------|---------------------------|-----------------------------|---------------------|
| Collector-emitter breakdown voltage $I_C = 10\text{ mA}$, $I_B = 0$ | $V_{(BR)CE0}$ | 45 60 80 | — — — | — — — | V |
| Collector-base breakdown voltage ¹⁾ $I_C = 100\text{ }\mu\text{A}$, $I_B = 0$ | $V_{(BR)CB0}$ | 45 60 100 | — — — | — — — | |
| Emitter-base breakdown voltage $I_E = 10\text{ }\mu\text{A}$, $I_C = 0$ | $V_{(BR)EB0}$ | 5 | — | — | |
| Collector-base cutoff current $V_{CB} = 30\text{ V}$, $I_E = 0$ $V_{CB} = 30\text{ V}$, $I_E = 0$, $T_A = 150\text{ °C}$ | I_{CB0} | — — | — — | 100 20 | nA μA |
| Emitter-base cutoff current $V_{EB} = 5\text{ V}$ | I_{EB0} | — | — | 10 | μA |
| DC current gain $I_C = 5\text{ mA}$, $V_{CE} = 2\text{ V}$ $I_C = 150\text{ mA}$, $V_{CE} = 2\text{ V}$ | h_{FE} | 25 40 63 100 25 | — — 100 160 — | — 250 160 250 — | — |
| Collector-emitter saturation voltage ¹⁾ $I_C = 500\text{ mA}$, $I_B = 50\text{ mA}$ | V_{CEsat} | — | — | 0.5 | V |
| Base-emitter voltage ¹⁾ $I_C = 500\text{ mA}$, $V_{CE} = 2\text{ V}$ | V_{BE} | — | — | 1 | |

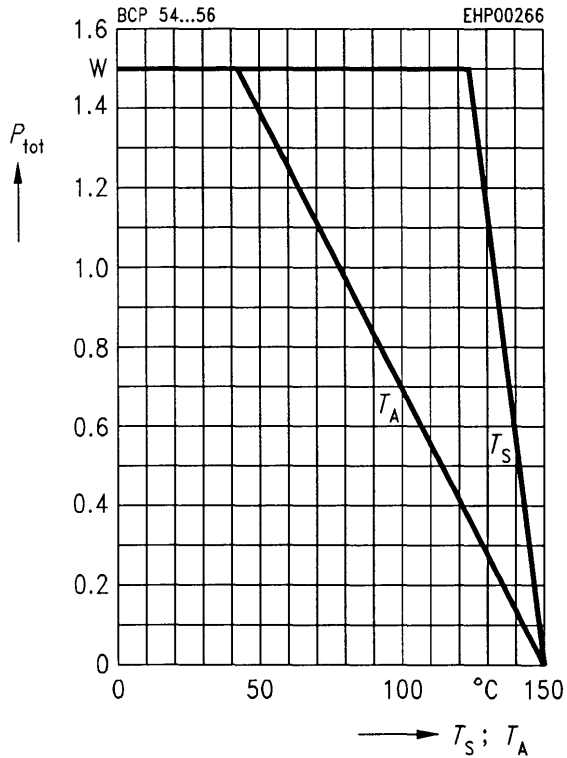
AC characteristics

| | | | | | |
|--|-------|---|-----|---|-----|
| Transition frequency $I_C = 50\text{ mA}$, $V_{CE} = 10\text{ V}$, $f = 100\text{ MHz}$ | f_T | — | 100 | — | MHz |
|--|-------|---|-----|---|-----|

¹⁾ Pulse test conditions: $t \leq 300\text{ }\mu\text{s}$, $D = 2\text{ %}$.

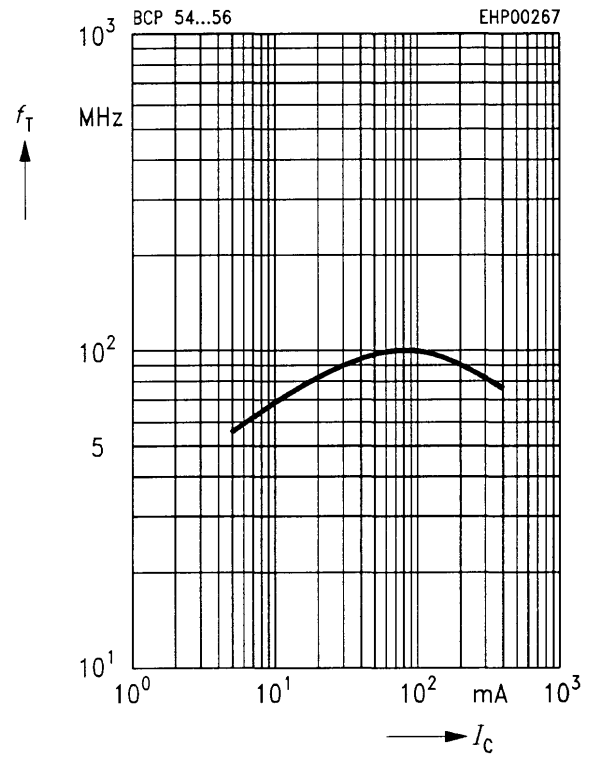
Total power dissipation $P_{tot} = f(T_A^*; T_S)$

* Package mounted on epoxy



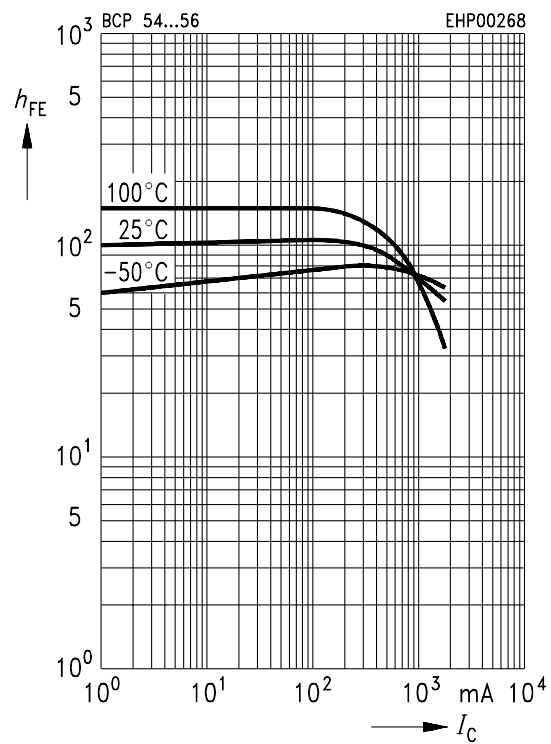
Transition frequency $f_T = f(I_C)$

$V_{CE} = 10\text{ V}$



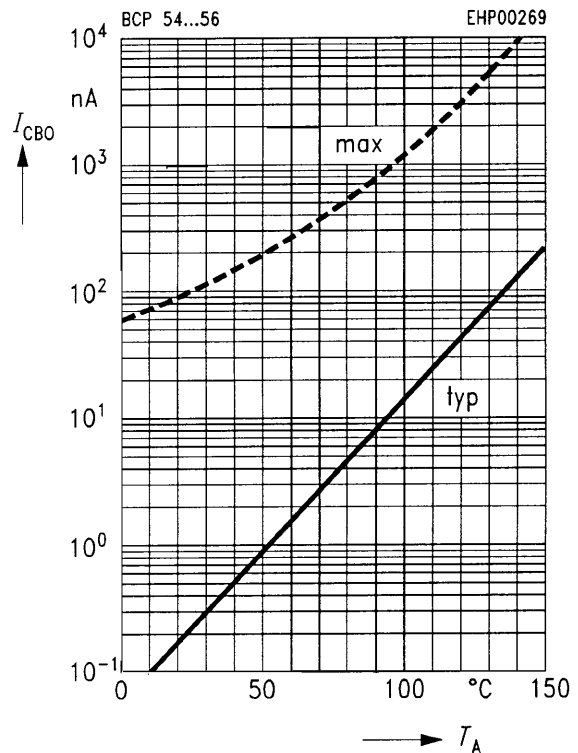
DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 2\text{ V}$



Collector cutoff current $I_{CBO} = f(T_A)$

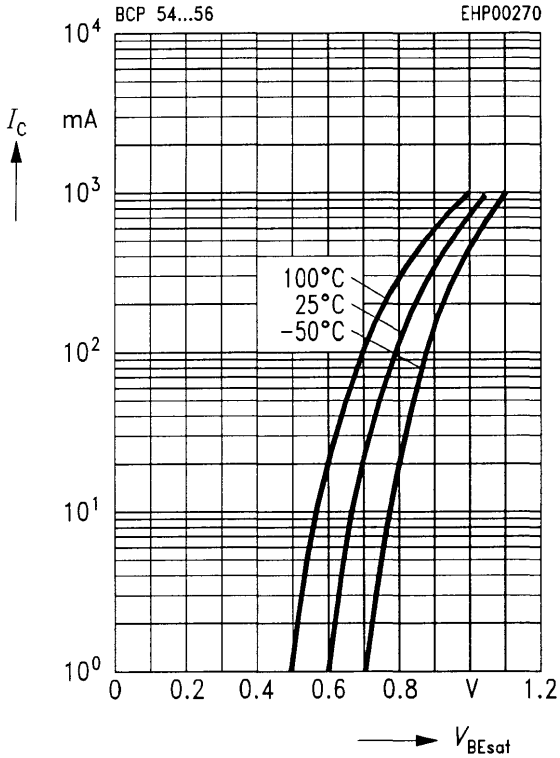
$V_{CB} = 30\text{ V}$



Base-emitter saturation voltage

$I_C = f(V_{BEsat})$

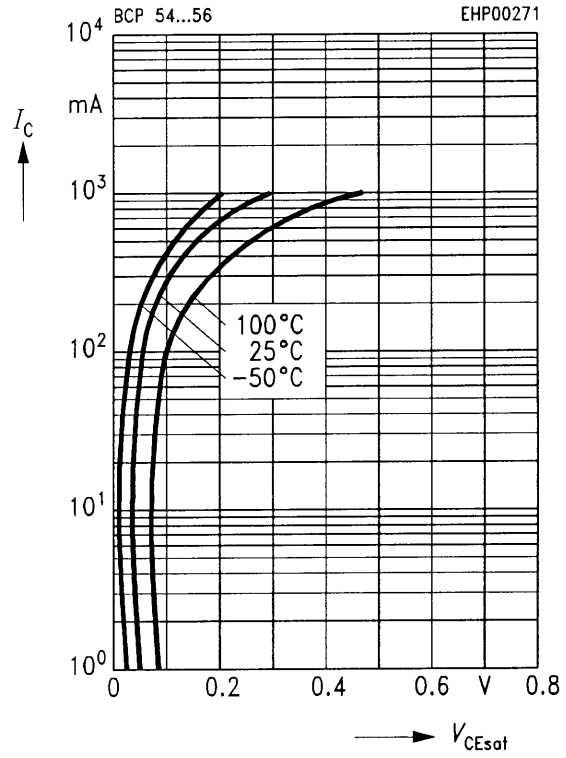
$h_{FE} = 10$



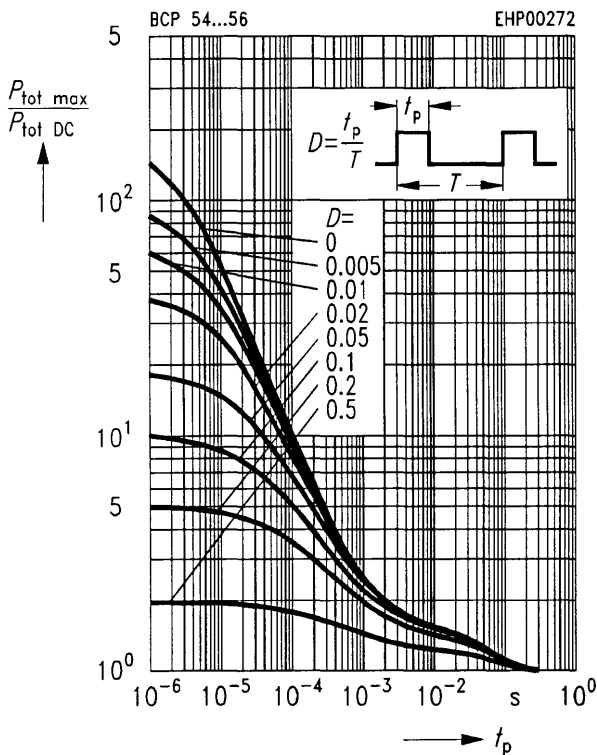
Collector-emitter saturation voltage

$I_C = f(V_{CEsat})$

$h_{FE} = 10$



Permissible pulse load $P_{tot max}/P_{tot DC} = f(t_p)$





LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

LittleDiode.com

Looking forward to providing you with the best possible service.